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(11)

EP 0 926 885 A2

(12)

EUROPEAN PATENT APPLICATION

(43) Date of publication: 30.08.1999 Builletin 1988/28

- (51) Int CLP: H04N 3/16
- (21) Application number: 98310547.7
- (22) Date of filing: 23.12,1998
- (84) Designated Contracting States:

 AT BE CH CY DE DK ES FI FR GB GR IE IT LI LU

 MC NL PT SE

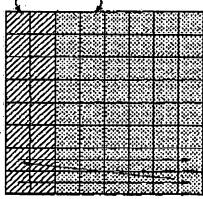
 Designated Extension States:

 AL LT LV MK RO SI
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- (54) Solid state image pickup apparatus
- (57) In a solid state image pickup apparatus having a plurality of photoelectric conversion elements including a standard eignal outputting photoelectric conversion element group for outputting standard eignals and an effective signal outputting photoelectric conversion element group for outputting effective signals, a scanner circuit for sequentially reading signals from the photoelectric elements, and a selector circuit for selectively reading an optional element group in the effective eignal outputting photoelectric conversion element group and the optional element group and the optional element group and the optional element group in the effective element group in the effective signal outputting photoelectric conversion element group and the option-toelectric conversion element group selected by the selector circuit.

FIG. 2A

PHOTOELECTRIC CONVERSION ELEMENT FOR STANDARD SIGNAL OUTPUT PHOTOELECTRIC CONVERSION ELEMENT FOR EFFECTIVE SIGNAL OUTPUT

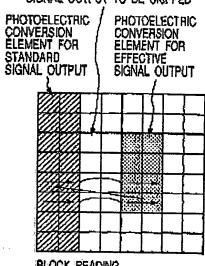


ALL PIXELS READING

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FIG. 2B

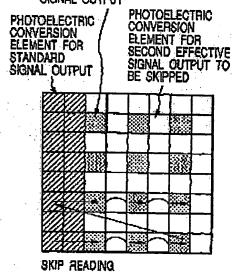
PHOTOELECTRIC CONVERSION ELEMENT FOR FIRST EFFECTIVE SIGNAL OUTPUT TO BE SKIPPED



BLOCK READING

FIG. 2C

PHOTOELECTRIC CONVERSION ELEMENT FOR EFFECTIVE SIGNAL OUTPUT



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BACKGROUND OF THE INVENTION

Field of the Invention

[0001] The present invention relates to a solid state image pickup apparatus with a photoelectric conversion unit, and more particularly to a solid state image pickup apparatus capable of reading an optional area of the photoelectric conversion unit in a pixel read mode such as a block read mode and a skip read mode, and to an image pickup system using such a solid state image pickup apparatus.

Related Background Art

[0002] Image information is widely used nowadays, and a variety of image data display methods are used in order to match various image data formats of multimedla.

[0003] High resolution image pickup devices are known which use CCD's for providing a resolution in excess of a high definition television (two million pixels). Most of these image pickup devices substantially deal with only still images, and it takes several seconds to capture an image of one frame. For example, a digital atili camera using such a high resolution image pickup device has the demerit that framing and focussing essential for the function of a camera cannot be executed in real time. In addition, since a frame rate is slow, a algnal accumulation time is long, which poses a problem of a degraded image quality to be caused by dark charges accumulated together with signal charges. Although a method of cooling an image pickup device is incorporated in order to suppress the generation of dark charges, this method is associated with a problem of an increased total consumption power.

[0004] A report which can solve the above problems is disclosed, for example, in "Four Million Pixels CMD Image Sensor", The Institute of Image Information and Television Engineers, ITE Technical Report, Vol. 21, No. 21, pp. 37-42, IPU 97-15, ca'97-7 (Mar, 1997). In this report, three terminals other than the gate of a CMD element of a four-terminal CMDS device are supplied with d.c. blases, and an output signal of a CMD element which is a source current is controlled by changing the pate potential. Of a full read mode, a ekip read mode, and a block read mode, the block read mode reads image information of all pixels in an optionally designated blockerea. The block read mode is realized by two procsesse, a process of setting a read start position and a process of reading an optionally designated block area. CMD elements disposed in a matrix are read by sequentially turning on and off a scan shift register.

[0005] However, although the report describes the block read of CMD elements of the CMO8 device, it does not describe how notes of CMD elements are

read. Since a CMO8 sensor manufactured by CMO8 processes has an SN ratio smaller than a CCD sensor. It is desired to improve an 6/N ratio also in the block read mode.

[0008] Noises generated in a CMOS type solid state image pickup device include random noises and fixed pattern noises. Random noises can be reduced by providing an empillier with each pixel of a CMO6 type solid etate image pickup device, and fixed pattern noisee can be reduced by subtracting noise data from picked-up image data. Although these techniques are well known, particular methods suitable for practice are not known.

SUMMARY OF THE INVENTION

[0007] It is an object of the present invention to faciliitete noise reduction also in reading data from an optionally selected area of a photoelectric conversion unit. [DDDB] In order to achieve the above object, an embodiment of the invention provides a solid state image pickup apparatus comprising: a plurality of photoelectric conversion elements including a standard signal outputting photoelectric conversion element group for outputting standard signals and an effective signal outputting photoelectric conversion element group for outputting effective signals; scanning means for sequentially reading signals from the photoelectric elements; and selecting means for eelectively reading an optional element group in the effective signal outputting photoelectric conversion element group, wherein the acanning means reads both the standard signal outputting photostectric conversion element group and the optional element group in the effective signal outputting photoelectric conversion element group selected by the selecting mesne.

[0009] Another embodiment of the invention provides an image pickup system comprising: a plurality of photoelectric conversion elements including a standard signal outputting photoelectric conversion element group for outputting standard signals and an effective signal outputting photoelectric conversion element group for outputting effective algorals; a scanning unit for sequenfielly reading signals from the photoelectric elements; a selecting unit for selectively reading an optional element group in the effective signal outputting photoslectric conversion element group, wherein the acanning unit reads both the standard eignal outputting photoelectric conversion element group and the optional element group in the effective eignal outputting photoelectric conversion element group selected by the selecting unit: a subtracting unit for subtracting signal components of the standard signal outputting photoelectric conversion group from signal components of the optional element group in the effective eignal outputting photoelectric conversion element group salected by the selecting unit; and an adjusting unit for adjusting a focus or an exposure in accordance with a signal output from the subtracting unit.

[0020] Figs. 9A, 9B and 9C are a circuit diagram of the selector circuit and timing charts lilustrating its operation.

[0021] Fig. 10 is a block diagram showing an image pickup system according to a second embodiment of the invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0022] Embodiments of the invention will be described in detail with reference to the accompanying drawings.

(Firet Embodiment)

[0023] Fig. 1 is a circuit diagram of a driver for driving a CMOS sensor constituted of photoelectric conversion elements each having two elements. Each photoslectric conversion element is constituted of one of PN junction photodiodes PD (1 to PD22, ... and a corresponding one of transfere translature ST11 to ST22, ... connected to the anodes of the photodiodes. A vertical selector circuit VSR sequentially outputs high level outputs V1 to V8 to sequentially activate vertical select lines HL1, HL2, ..., and a horizontal selector circuit HSR sequentially outputs high level outputs H1 to H8 to sequentially turn on horizontal transfer MOS translators HT1 to HT8. Therefore, image charges accumulated in respective pixels are time acquentially read from the respective vertical output lines HVI to HV8 to an output line HOL and output via an amplifier AMP.

[0024] A reset MOS translator RES turns on the output line HOL to reset the output line HOL each time the pixel charges are output. Of the photoclodes PD11 to PD22, ... the ancdes of the photoclodes PD11, PD12, PD21, PD22, PD31, ... are shielded to pick up tark charges.

[0025] In this CMO8 sensor, as photons are implinged upon a PN junction of each photoelectric conversion element constituting a pixel, pairs of electrons and holes are generated and accumulated in the deletion layer and the transfer MOS transistor ST11, ... reads the electrons or holes. The CMOS sensor including the horizontal and vertical selector circuits is manufactured by CMOS processes and therefore called a CMOS sensor.

[0026] In this embediment, although a passive type MOS sensor is used, an amplification type AMI (amplification type MOS sensor), a CMD (charge modulation type CMOS sensor), or an APS (active pixel type sensor) may also be used.

[0027] Figs. 2A to 2C are conceptual diagrams illustrating read methods of the solid state image pickup apparatus used an area sensor described above. Fig. 2A illustrates an example of a full read mode in this mode, standard signals of dark charges are read from a light shielded standard signal outputting photoslactric conversion slament group in left two columns as viewed in

[0010] A still further embodiment of the invention provides an image pickup system comprising: a plurality of photoelectric conversion elements including a standard algnai outputting photoelectric conversion element group for outputting standard algnals and an effective aignal outputting photoelectric conversion element group for outputting effective signals; a scanning unit for aequentially reading signals from the photoslectric elements; a selecting unit for selectively reading an optionat element group in the effective signal outputting photoelectric conversion element group, wherein the scanning unit reads both the standard signal outputting photoslectric conversion sisment group and the optional siement group in the effective signal outputting photoslectric conversion element group selected by the selecting unit; a subtracting unit for subtracting signal components of the standard signal outputting photoelectric conversion group from signal components of the optional element group in the effective signal outputting photoelectric conversion element group selected by the selecting unit; a signal processing circuit for processing a algnal output from the aubtracting unit; a awitching unit for ewitching between a still image mode and a moving image mode; and a controlling unit for controlling to make the selecting unit to select all photoelectric conversion elements if the switching unit selects the still image mode, and to make the selecting unit to select a predetermined area smaller than a whole area of the effective algnal outputting photoelectric conversion element group if the awitching means selects the moving so image mode.

[0011] Other objects and features of the present invention will become apparent from the following detailed description of embodiments when read in conjunction with the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

[0012] Fig. 1 is a circuit block diagram of a solid state image pickup apparatus according to a first embodiment of the invention.

[9013] Figs. 2A, 2B and 2C are conceptual diagrams illustrating each read mode of the solid state image pick-up apparatus of the first embodiment.

[0014] Fig. 3 is a timing chart illustrating a full read mode according to the first embediment.

[0015] Fig. 4 is a fiming chart illustrating a block read mode according to the first embodiment.

[0016] Fig. 5 is a timing chart illustrating a skip read mode according to the first embodiment.

[0017] Fig. 6 is a timing chart illustrating the full read mode according to the first embodiment.

[9015] Figs. 7A and 7B are block diagrams of a eignal processing circuit used in each read mode of the first embodiment.

[0019] Figs. 8A and 8B are a circuit diagram of a selector circuit and a table illustrating its operation according to the first embodiment.

Fig. 2A, whereas effective signals of photo charges are read from an effective signal outputting photoelectric conversion element group in an effective read area. Fig. 2B lilustrates an example of a block read mode. In this mode, standard signals of dark charges are read from the light shielded photoelectric conversion element group in left two columns, whereas effective signals of photo charges are read from the effective signal outputting photoelectric conversion element group only in a designated block area without reading other areas, in this example only from two pixels on one line. Fig. 2C illustrates an example of a skip read mode. In this mode, standard signals of dark charges are read from the light shielded photoelectric conversion element group in left two columns, whereas effective signals of photo chargse are read from the effective signal outputting photoslectric conversion element group by skipping every sec-

[0028] The operation of the full read made will be described with reference to the timing chart shown in Fig. 3. The vertical selector circuit VSR outputs first a high level output VI to activate the vertical select line HL1. and the horizontal selector circuit HSR sequentially outputs high level outputs H1 to H8 to acquentially turn on the horizontal transfer MOS transistors HT1 to HT8. Therefore, image charges accumulated in respective pixels are time sequentially read from the respective vertical output lines HV1 to HV8 to the output line HOL and output via the amplifier AMP. While the horizontal selector circuit HSR sequentially outputs the high level outputs H1 to H8, the reset MOS transistor RES is turned on to reset the output line HOL and correspondlay a entremit has a tramele notatevinos situates pical charges are read, to thereby eliminate the influence of adjacent pixels. As shown in Fig. 3, an output of the ampillier AMP takes a low potential level corresponding to pixel charges of the pixel photodiodes PD11 to PD18. Thereafter, the vertical selector circuit VSR outputs a high level output V2 to repeat the above operations.

[0039] The light shielded pixel photodiodes PD11 and PD12 of the standard signal outputting photoelectric conversion element group output standard signals representative of dark charges. A pair of first effective signals is output from the pixel photodiodes PD13 and PD14, a pair of second effective signals is output from the pixel photodiodes PD15 and PD16, and a pair of third effective signals is output from the pixel photodiodes PD17 and PD18. Next, the light ethielded pixel photodiodes PD21 and PD22 of the standard signal outputting photoelectric conversion element group output standard signals representative of dark charges, and operations elmilar to the above-described operations are repeated. In this manner, all pixels disposed in a matrix are read.

[0030] Fig. 4 is a firming chart illustrating a block read mode of the solid state image pickup apparatus shown in Fig. 2B. It is assumed that the designated block contains the pixel photodiodes PD15 and PD18.

[0031] The vertical selector circuit VSR outputs first a high level output V1 to activate the vertical select line HL1, and the horizontal selector circuit HSR sequentially outputs high level outputs H1, H2, H5, and H6 to sequentially turn on the horizontal transfer MOS translators HT1, HT2, HT5, and HT6. Therefore, image charges accumulated in respective pixels are time sequentially read from the respective vertical output lines HV1, HV2, HV5, and HV8 to the output line HOL and output via the amplifier AMP.

[0032] While the horizontal selector circuit HSR sequentially outputs the high level outputs H1, H2, H5, and H8, the reset MOS translator RES is turned on to reset the output line HOL and corresponding photoelectric conversion element each time the pixel charges are read, to thereby eliminate the influence of adjacent pixels. As shown in Fig. 4, an output of the amplifier AMP takes a low potential level corresponding to pixel charges of the pixel photodiodes PD11 and PD12 of the standard signal outputting photoelectric conversion element group and the pixel photodiodes PD15 and PD16 of the first effective eignal outputting photoelectric conversion element group.

[0033] Fig. 8 is a timing chart illustrating a skip read mode of the solid state image pickup apparatus shown in Fig. 2C. In this skip read mode, every second pixels in the horizontal and vertical directions are read in the pixel area for reading effective signals.

[0034] The vertical selector circuit VSR outputs first a high level output V1 to activate the vertical select line HL1, and the horizontal selector circuit HSR sequentially outputs high level outputs H1, H2, H3, H5, H7, ... to sequentially turn on the horizontal transfer MOS transistors HT1, HT2, HT3, HT5, HT7, Therefore, image charges accumulated in respective pixels are time sequentially read from the respective vertical output lines HV1, HV2, HV3, HV5, HV7, ... to the output line HOL and output via the amplifier AMP.

[9035] While the horizontal selector circuit HSR sequentially outpute the high level outpute H1, H2, H3, H5, H7, ..., the reset MOS translator RES is turned on to reset the output line HOL and corresponding photoelectric conversion alarment each time the pixel charges are read, to thereby aliminate the influence of adjacent pixels. As shown in Fig. 5, an autput of the ampilifer AMP takes a low potential level corresponding to pixel charges of the pixel photoelectric conversion element group and the pixel photoelectric conversion element 9 PD17 of the first effective signal outputting photoelectric conversion element group.

[0038] Fig. 6 is a timing chart illustrating another full read mode. As different from the full read mode shown in Fig. 3, odd number pixel photodiodes PD13, PD15, and PD17 of the first effective signal outputting photoelectric conversion element group are used for reading first effective signals, and even number pixel photodiodes PD14, PD16, and PD18 of the second effective

signal outputting photoelectric conversion element group are used for reading second effective signals. In this case, both the horizontal and vertical selector circuits HSR and VSR operate in a similar manner.

[0097] Next, an Image signal processing circuit for processing an image signal as illustrated in Figs. 3 to 6 will be described with reference to Figs. 7A and 7B. Referring to Fig. 7A, a vertical selector circuit V6R11 activates each horizontal line of a photoelectric conversion unit 10 having photoelectric conversion elements disposed in a matrix, and a horizontal selector circuit HSR12 operates to sequentially output from an amplifier AMP image signals read from the standard signal outputting photoelectric conversion element group and from the effective eignal outputting photoelectric converalon element group. An output of the photoelectric conversion apparatus is input to a standard voltage generating device 14 during an output period of the standard signal outputting photoslactric conversion element group, and the standard voltage generating device 14 20 generates a standard voltage. If the standard signal outputting photoelectric conversion element group contains two pixels, the standard voltage generating device 14 generates the standard voltage which is, for example, an average of two standard signals. During an output period of the effective algnal outputting photoelectric conversion element group, an output of the solid state lmage pickup apparatus is input to a clamp circuit 13 and clamped by the standard voltage supplied from the standard voltage generating device 14. An image signal picked up from the effective signal outputting photoslectric conversion element group is subtracted by the standard voltage corresponding to dark charges on the horizontal line to thereby obtain a correct Image signal corresponding to only image charges. The standard voltage generated by the standard voltage generating device 14 is reset after one horizontal line is read. The standard voltage generating device 14 again generates a standard voltage from standard signals read from atenderd algnal outputting photoelectric conversion element group on the next horizontal line. The image algnal read from the effective signal outputting photoelectric conversion element group on the next horizontal line is subtracted by the new standard voltage.

[0038] An output of the clamp circuit 13 is converted thio a digital image signal by an A/D converter 15. The digital signal is processed by an unrepresented signal processing circuit for shading correction, gamma correction and the like. In this embodiment, the standard signal outputting photoslectric conversion signant of group contains two pixels in each line. The number of pixels is not limited only to two, but a desired number of pixels may be used so long as an optimum clamp is possible.

[0039] Fig. 7B is a block diagram of another signal processing circuit. An image signal from an amplifier AMP is supplied via a sample/hold circuit to an AfD converter circuit 18 whereat it is converted into a digital im-

age signal. The digital image signal is supplied to a digital signal processing circuit 17. The digital signal proceeeing circuit 17 calculates an everage of standard eignala representative of dark charges output during the output period of the standard signal outputting photoelectric conversion element group, and uses the average as the standard voltage. Each image signal of the same horizontal line output during the output period of the effective eignal outputting photoelectric conversion element group is subtracted by the standard voltage to thereby eliminate noise components in the effective signal pixel. The effective image signal with eliminated noise components is the reafter processed for shading correction, gamma correction and the like. This signal processing circuit can be febricated on the same chip as the photoelectric conversion unit manufactured through CMOS processes so that the solid state image pickup apparatus including the signal processing circuit can be manulactured.

[0040] Figs. 8A and 8B are a circuit diagram of a decoder circuit constituting the horizontal selector circuit HSR shown in Fig. 1 and a table illustrating its operation. The horizontal circuit HSR is required in a pixel read mode, typically in the full read mode, to sequentially turn on the horizontal transfer MOS switches HT1 to HT8 and sequentially output the high level outputs H1 to H8 in order to pick up pixel charges from the vertical output lines H1 to H8. To this end, the operation of the logical table shown in Fig. 8B is performed. Specifically, pulse eignals S1 to S3 and inverted pulse eignals S1 to S3 obtained from inverters IN9 to INII are selectively supplied each of logical product gates NAND1 to NAND8. Inverters IN1 to IN8 connected to NAND1 to NAND8 sequentially output high level outputs H1 to HB. This operation is repeated to ecan the whole matrix of the area sensor. This operation is also applied to the vertical selactor circuit VSR to sequentially output high level outputs HL1 to HL8, although a higher repetition frequency le used in this case.

[0041] In the block read mode using this horizontal eelector circuit HSR, pulse eignale S1 to S3 sequentially outputting high level outputs H1, H2, H5, and H6 are supplied, as shown in Fig. 4. In the skip read mode, pulse signals S1 to S3 sequentially outputting high level outputs H1, H2, H3, H5, ... on the first horizontal line and H1, H2, H4, H6, ... on the next horizontal line are supplied, as shown in Fig. 5. These operations are also applied to the vertical selector circuit.

[0042] This horizontal selector circuit HSR can be tormed on the same chip as the photoelectric conversion unit to have a smaller area and volume through CMOS processes. As compared to a CCD sensor, the number of manufacture processes can be reduced considerably.

[D043] Next, the horizontal selector circuit HSR made of a shift register will be described with reference to Figs. 9A to 9C. Referring to Fig. RA, clocks PH1B and BLKB of inverted clocks PH1 and BLK are input to the horizontal selector circuit HSR. The operation in the full read mode will be described with reference to the timing chart shown in Fig. 9B. In Fig. 9B, the clocks PH1B and BLKB are omitted.

[0044] When a high level start pulse PHST is input, it is tatched by the first stage flip-flop circuit, and a shift pulse is output from OUT1 as the high-level output H1 at a timing shown in Fig. 9B. The latched high level pulse is sequentially transferred to the flip-flop circuits at succeeding stages in response to clock pulses PH1 and PH2. In this manner, shift pulses are sequentially output from OUT2, OUT3, ... as the high level outputs H2, H3.

[0045] The operation of the block read mode and skip read mode will be described with reference to the timing that shown in Fig. 9C. In the block or skip read mode, the clock BLK is set to the high level so that the high level start pulse PHST can be sequentially transferred to the flip-flop circuits at successding stages by skipping the flip-flop circuit with OUT2. In this manner, output pulses shown in Figs. 4 and 5 can be obtained.

[0046] As described above, in this embodiment, an image algnal picked up during the output period of the effective algnal outputting photoelectric conversion element group is subtracted by a standard voltage representative of dark charges. Therefore, an image signal in a desired pixel area having a good S/N ratio and a good image quality can be obtained. A reliable operation of auto focuseing and auto exposure for an image in a dark scene can be ensured.

[0047] In the above embodiment, a standard image algnal representative of dark charges is read from the atendard signal outputting photosenalitive conversion element group before an effective image algnal is read from the effective signal outputting photosensitive conversion element group is read. The standard image signal may be read from the standard signal outputting photoelectric conversion element group after the effective image signal is read from the effective signal outputting photoelectric conversion element group, with a similar operation as above and a high S/N ratio as above. In this case, the light shielded area shown in Figs. 2A to 2C from which dark charges are read is disposed on the right side in each of Figs. 2A to 2C, and the clamp circuit is provided with a memory of one line capacity. After the atendard voltage generating device generates the standard voltage, the clamp circuit clamps image signals. The operation of the horizontal selector circuit is the same as that described above.

[0048] The standard image signals may be read from the standard signal cutputing photoelectric conversion element group before and after the effective image signals are read from the effective signal outputting photoelectric conversion element group, with similar advantages described above. Also in this case, an area from which darkcharges are read is disposed near the central area of each line of an area sensor. The standard image signals representative of dark charges are picked up at

timings when the standard signal generating device generates the standard voltage.

(Second Embodiment)

[D048] Various functions can be obtained by selectively reading the pixel area in the block and skip read modes of a multi-pixel sensor (particularly an area sensor).

(1) Auto Focussing Sensor

[0050] An in-locus state is determined from an image having a best contrast among a plurality of images time sequentially picked up by changing the focal length of the lens, in determining the in-focus state, it is not necessary to use image signals from all pixels, but only those signals from an area near a subject to be focussed can be used. By selectively outputting image signals from such an area, high speed auto focussing is possible.

[0051] More specifically, the block read mode is used. in the block read mode, a subject to be focussed is poeltioned at the center of the area sensor and the block around this center is designated. Under these conditions, the image signals of the photoelectric conversion elements in the block and the image alguals representative of dark charges in the standard algnet outputting photoelectric conversion element group on the center lines are read. The noise signals are subtracted from the image signals of the photoelectric conversion elements in the block to obtain correct image signals. Correct image signals are picked up a plurality of times by changing the local length. For example, if the image eignal has a clear contour, it is judged as an in-focus state. At this point, the auto focusaing operation is terminated, and the subject is photographed. Since a predetermined narrow area of the block is read, auto focussing can be performed at high speed and in short time.

(2) Autometic Exposure (AE) Sensor

[D052] An image of a subject is picked up by changing an exposure time. In accordance with the picked-up image signals, the exposure time for actual photographing is determined. Similar to an auto focuseing sensor, it is not necessary to use image signals of all pixels, but only those signals in an area near the subject whose exposure is adjusted can be used. By selectively outputting only the image signals in the area near the subject, AE can be performed at high speed.

[0053] An exposure time of a still image camera is determined in accordance with a light amount in a central area of an angle of view. Therefore, similar to auto focuseing, this central area is used as a block in the block read mode. By subtracting noise components, a correct exposure time can be determined at high speed. Also in a video camera which photographs a moving image, a continuously changing light amount of a subject is detected at high speed in the block read mode, in accordance with an image output level in the block read mode, a stop-down degree of an aperture corresponding to an optimum exposure time is determined. In accordance with the stop-down degree, the light amount of the exposure point incident upon the area sensor is regulated to thereby set a light amount providing linear characteristics. In this manner, an image eignal of high sensitivity can be obteined.

(3) Trimming

[0054] An electronic zooming is possible by cutting and picking up only a partial area of an image. In a digital camera, a high precision image output with a large data amount or a poor quality image output with a small data amount can be selectively obtained through image thinning.

(4) Switching between Still Images and Moying Images

[0055] A still image is picked up with a sensor having one million and four hundred pixels, whereas a moving image of NTSC is output by reading image signals of a quarter of 1400 thousand pixels, or 350 thousand pixels. An image of 1400 thousand pixels has too last a data rate and does not match a resolution of NTSC specifications, e.g., 525 × 460 pixels. In reading a still image, therefore, the full read mode is used and a standard voltage representative of dark charges on each line from the standard signal outputting photoelectric conversion element group is subtracted from the effective image algnal to thereby obtain a high S/N image signal. In reading a moving image of NTSC, about a quarter of pixels is read so that a moving image signal can be read at high speed in the skip or block read mode. By selectively using the full read mode and the skip or block mode, a good 8/N image signal can be obtained.

[0056] Next, an image pickup system having the functions (1) to (4) described above will be described with reference to Fig. 10.

[0067] Referring to Fig. 10, reference numerals 11 to 15 represent the same components as those shown in Fig. 7A. A reference numeral 50 represents a signal processing circuit for processing an A/D converted signal, such as for color processing. Reference numeral 51 represents an AF detector circuit (AF detecting phase circuit) for detecting a signal for AF from the signal processing circuit. Reference numeral 52 represents an AE detector circuit (AE detecting phase circuit) for detecting a signal for AE. Reference numeral 53 represents a control circuit for controlling the whole of the image pickup eyetem. Reference numeral 54 represents a selector circuit driving circuit (selection unit driving circuit) for driving the horizontal selector circuit 12 and vertical selector circuit 11. Reference numeral 55 represents a shutter driving circuit for driving a shutter 58.

Reference numeral 58 represents a lens driving circuit for driving a lens 57. Reference numeral 59 represents a ewitching circuit for ewitching between a etili image mode and a moving image mode.

[0058] First, the operations of AF and AE will be described.

[0059] For the AF and AE operations, the control circult 53 controls via the selector circuit driving circuit 54 the horizontal and vertical selector circuits 12 and 11 in order to output signals from photoelectric conversion elements in a necessary area of the photoelectric conversion unit 10. Output signals selected by the horizontal and vertical selector circuits 12 and 11 are supplied to the clamp circuit whereat noises are eliminated, and are supplied via the A/D converter 15 to the signal processing circuit 50. Signals for AF and AE processed by the signal processing circuit are input to the AF and AE detector circuits 61 and 52. In accordance with these signals for AF and AE, the control circuit 53 controls via the shutter and lens driving circuits 55 and 58 the shutter and lens to thereby perform AF and AE operations. [0080] Next, an operation of switching between still images and moving images will be described.

[0061] When a still image mode is set by the switching circuit 57, the control circuit 53 controls via the selector circuit driving circuit 54 the horizontal and vertical selector circuits 12 and 11 in order to output signals from all the photoelectric conversion elements in the photoelectric conversion elements are removed by the clamp circuit 13, and the output signals with the noises removed are input via the A/D converter circuit to the signal processing circuit 50 performs color processing and the like to output a still image signal.

[0062] When a moving image mode is set by the switching circuit 59, the control circuit 52 performs the skip read operation by controlling the horizontal and vertical selector circuits 12 and 11, or the block read operation may be performed by focussing light upon an area nearthe central area of the photoelectric conversion unit by controlling the iens.

[D053] Noises in each signal output from the photoslactric conversion element are eliminated by the clamp circuit 13. The image signal with noises removed is input via the A/D converter circuit 15 to the signal proceeding circuit 50. The eignal proceeding circuit 50 performs color proceeding and the like to sequentially output moving image signals.

[0084] Noises may be removed by the signal processing circuit as described with Fig. 7B, not by the clamp circuit 13 described above.

[0065] According to the first and second embodiments, in the block read mode of a CMOS eeneor, notees can be suppressed so that auto focuseing and auto exposure most suitable for video cameras and digital cameras can be performed.

[0088] Both in the block and skip read modes, an im-

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age signal with cark charges being removed can be obtained. Therefore, a high quality block image eignal can be obtained at high epeed.

Claims

A solid state image pickup apparatus comprising:

a plurality of photoelectric conversion elements including a standard signal outputting photoelectric conversion element group for outputting standard signals and an affective signal outputting photoelectric conversion element group for outputting effective signals;

scanning means for sequentially reading eignals from said photoelectric elements; and selecting means for selectively reading an optional element group in the effective signal outputting photoelectric conversion element \$9 group,

wherein eald ecanning means reads both the standard signal outputting photoelectric conversion element group and the optional element group in the attactive signal outputting photoelectric conversion element group selected by said selecting means.

- A solid state image pickup apparatus according to claim 1, wherein the standard eignal outputting photoelectric conversion element group is a plurality of light shielded photoelectric conversion elements.
- A solid state image pickup apperatus according to claim 1 or 2, wherein said scanning means include a shift register, and said selecting means include means for changing a clock path of the shift register.
- A solid state image pickup apparatus according to claim 1 or 2, wherein said scanning means include a decoder.
- 5. A solid state image pickup apparatus according to claim 1 or 2, wherein standard signals from the standard signal outputting photoelectric conversion element group are output before effective signals from the effective eignal outputting photoelectric conversion element group are output.
- 6. A solid state image pickup apparatus according to claim 1 or 2, wherein standard signals from the standard eignal outputting photoelectric conversion element group are output after effective eignals from the effective eignal outputting photoelectric conversion element group are output.
- A solid state image pickup apparatus according to claim 1 or 2, wherein standard signals from the

standard signal outputting photoelectric conversion element group are output before and after effective elgnale from the effective elgnal outputting photoelectric conversion element group are output.

- 8. A solid state image pickup apparatus according to claim 1 or 2, wherein photoelectric conversion elements of the effective signal outputting photoelectric conversion element group are disposed in a matrix.
- 6. A solid state image pickup apparatus according to claim 1, wherein the standard signal outputting photoelectric conversion element group is a light shielded photoelectric conversion element.
- 10. A solid state image pickup apparatus according to claim 1 or 2, further comprising subtracting means for subtracting signal components of the standard signal outputting photoelectric conversion group from eignal components of the optional element group in the effective eignal outputting photoelectric conversion element group selected by said selecting means.

11. An image pickup system comprising.

a plurality of photoelectric conversion elements including a standard signal outputting photoelectric conversion element group for outputting standard signals and an effective signal outputting photoelectric conversion element group for outputting effective signals;

scanning means for sequentially reading signals from said photoelectric elements;

eelecting means for selectively reading an optional element group in the effective signal outputting photoelectric conversion element group, wherein said scanning means reads both the standard eignal outputting photoelectric conversion element group and the optional element group in the effective eignal outputting photoelectric conversion element group selectad by said selecting means;

subtracting means for subtracting signal components of the standard signal curputting photoelectric conversion group from signal components of the optional element group in the sftactive signal outputting photoelectric conversion stamant group selected by said selecting means; and

adjusting means for adjusting a focus or an exposure in accordance with a signal output from eald subtracting means.

12. An image pickup system comprising

a plurality of photoelectric conversion elements

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including a standard signal outputting photoslectric conversion element group for outputting standard algnale and an effective eignal outputting photoelectric conversion element group for outputting effective algoria; acanning means for sequentially reading signais from said photoslectric elements; selecting means for selectively reading an optional element group in the effective eignal outputting photoelectric conversion element 10 group, wherein said scanning means reads both the standard signal outputting photoelectric conversion element group and the optional element group in the effective signal outputting photoelectric conversion element group select- 18 ed by said selecting means; subtracting means for subtracting signal components of the standard signal outputting photo electric conversion group from signal components of the optional element group in the ef- 20 fective signal outputting photoelectric converalon alement group selected by said selecting

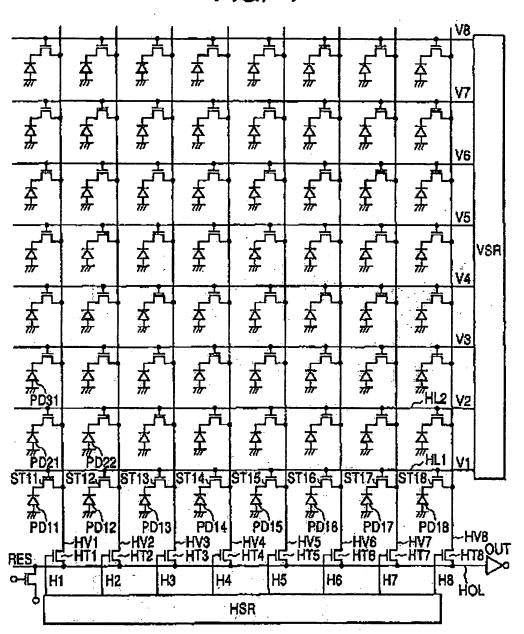
meana: a signal processing circuit for processing a signal output from said subtracting means: switching means for switching between a still image mode and a moving image mode; and controlling means for controlling to make said selecting means to select all photoelectric conversion elements in the effective signal outputting photoelectric conversion element group if said switching means selects the still image mode, and to make said selecting means to select a predetermined area smaller than a whole area of the effective signal outputting photoslectric conversion element group if said switching means selects the moving image mode.

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FIG. 1



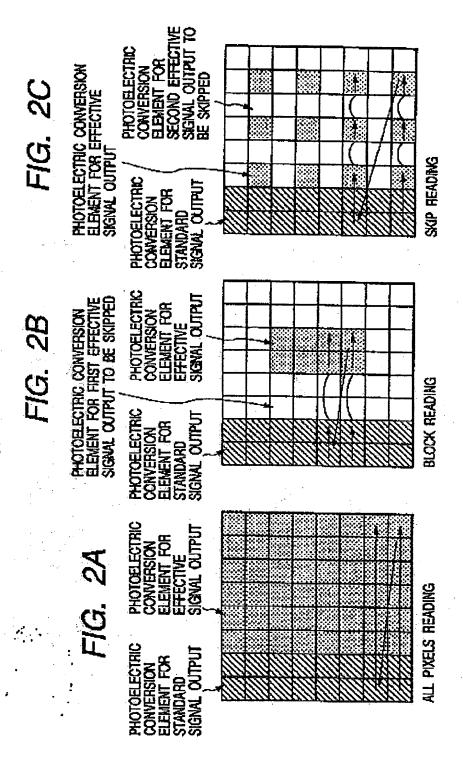


FIG. 3

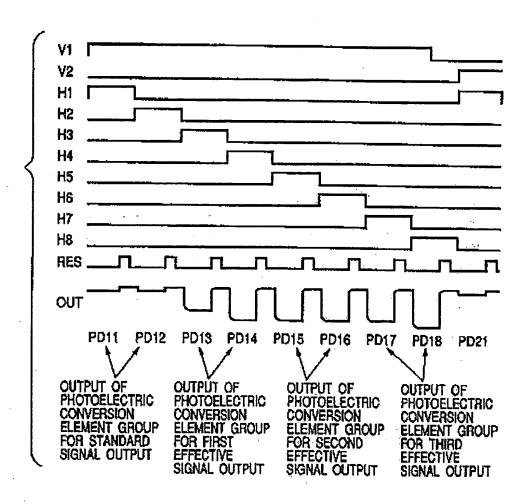


FIG. 4

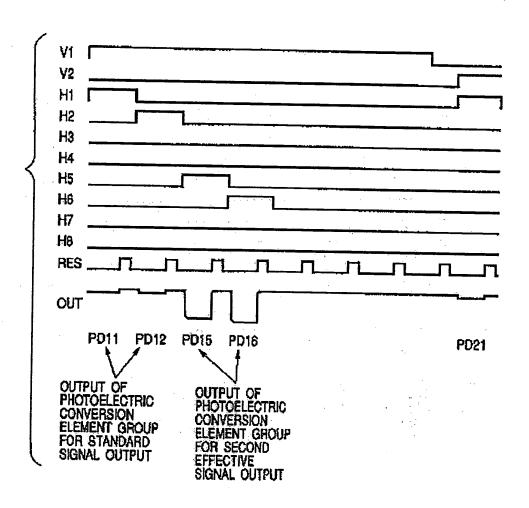


FIG. 5

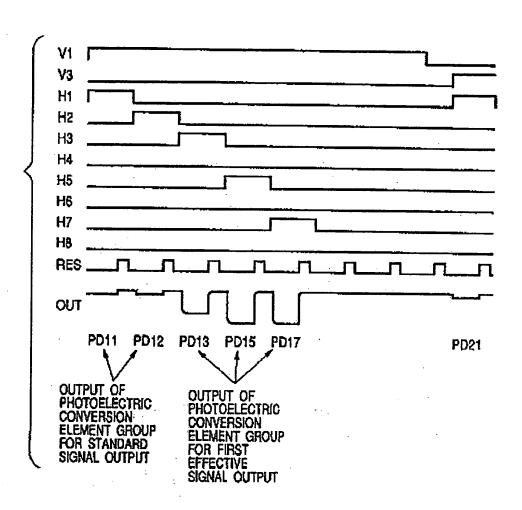
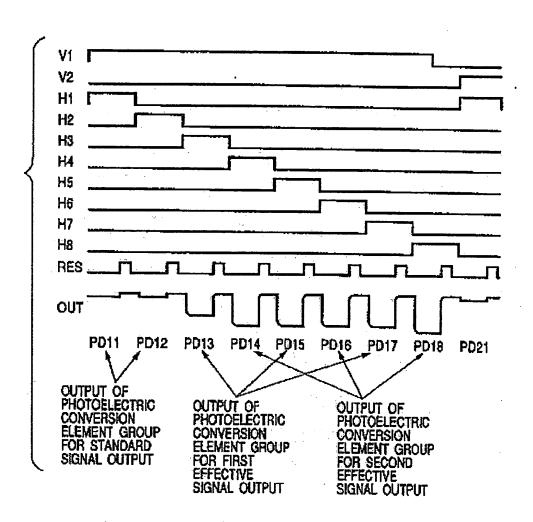


FIG. 6



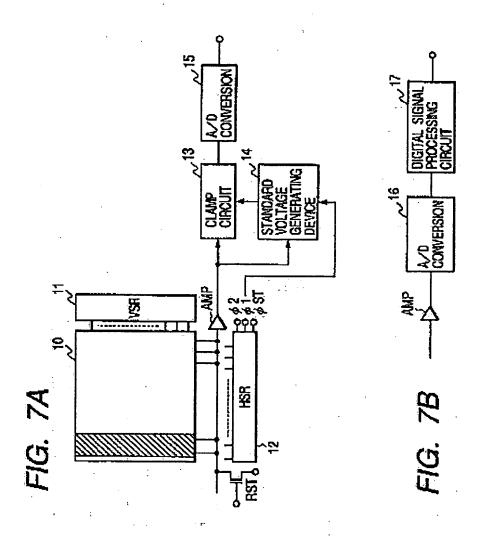


FIG. 8A

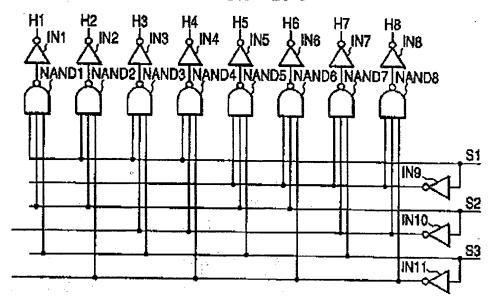


FIG. 8B

81	52	S3	Н1	H2	НЗ	H4	H5	H6	H7	Н8
1	1	1	1	0	0	0	0	0	0	0
1	1	0	0	1	0	0	0	0	0	0
1	0	1	0	0	1	0	0	0	0	0
1	0	0	0	0	0	1	0	0	0	0
0	1	7-	0	0	0	0	1	0	0	Đ
0	1	0	0	0	0	0	0	1	0	0
0	0	1	0	- 0	0	0	0	0	1	0
0	0	0	Đ	0	0	0	0	0	0	1

FIG. 9A

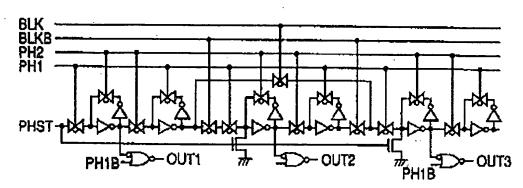


FIG. 9B

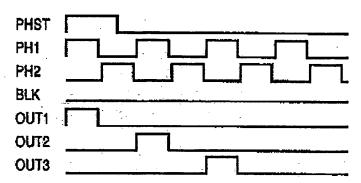


FIG. 9C

